

# PIMP32-Q

50 V, 500 mA PNP/PNP Resistor-Equipped double Transistor (RET); R1 = 2.2 k $\Omega$ , R2 = 10 k $\Omega$ 

16 February 2022

**Product data sheet** 

## 1. General description

PNP/PNP Resistor-Equipped double Transistor (RET) in a small SOT457 (SC-74) Surface-Mounted Device (SMD) plastic package.

NPN/NPN complement: PIMN32-Q NPN/PNP complement: PIMC32-Q

### 2. Features and benefits

- 500 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- · Reduces component count
- Reduces pick and place costs
- Qualified according to AEC-Q101 and recommended for use in automotive applications

## 3. Applications

- Digital applications
- Cost-saving alternative to BC807-Q series in digital applications
- · Control of IC inputs
- Switching loads

## 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Per transistor	Per transistor							
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-	-50	V	
Io	output current			-	-	-500	mA	
R1	bias resistor 1 (input)		[1]	1.54	2.2	2.86	kΩ	
R2/R1	bias resistor ratio		[1]	4.1	4.55	5		

[1] See section "Test information" for resistor calculation and test conditions.



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## 5. Pinning information

**Table 2. Pinning information** 

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1		O1 I2 GND2
2	I1	input (base) TR1		
3	O2	output (collector) TR2	<u> </u>	R1 R2
4	GND2	GND (emitter) TR2		TR2
5	12	input (base) TR2	<u>o</u> H1 H2 H3	TR1 R2 R1
6	01	output (collector) TR1	SC-74; TSOP6 (SOT457)	
				GND1 I1 O2 aaa-019790

## 6. Ordering information

**Table 3. Ordering information** 

Type number	Package	Package					
	Name	Description	Version				
PIMP32-Q	SC-74; TSOP6	plastic, surface-mounted package (SC-74; TSOP6); 6 leads	SOT457				

## 7. Marking

### **Table 4. Marking codes**

Type number	Marking code
PIMP32-Q	4J

## 8. Limiting values

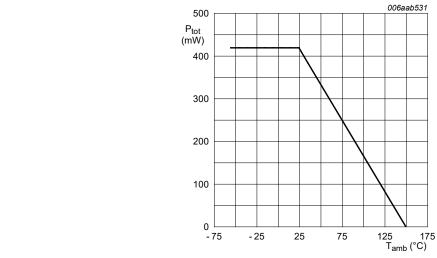
### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transisto	or		'	'	'	
V <sub>CBO</sub>	collector-base voltage	open emitter		-	-50	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-50	V
$V_{EBO}$	emitter-base voltage	open collector		-	-5	V
VI	input voltage			-12	5	V
Io	output current			-	-500	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	290	mW
Per device	·		,			
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	420	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

 $[1] \quad \text{Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, } 35~\mu\text{m copper, tin-plated and standard footprint.}$ 

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FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint

Fig. 1. Per device: Power derating curve

## 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Per transistor	Per transistor							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	432	K/W	
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	-	105	K/W	
Per device	Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	298	K/W	

[1] Device mounted on an FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint.

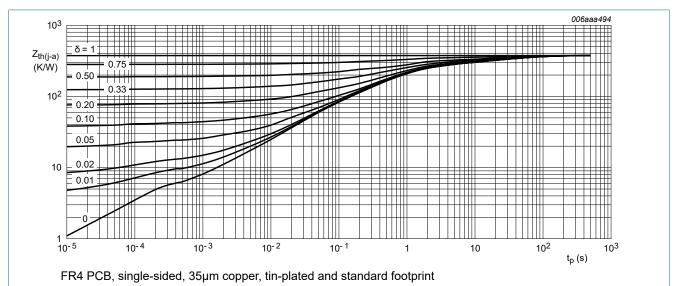


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

50 V, 500 mA PNP/PNP Resistor-Equipped double Transistor (RET); R1 = 2.2 k $\Omega$ , R2 = 10 k $\Omega$ 

## 10. Characteristics

**Table 7. Characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	or						
V <sub>(BR)CBO</sub>	collector-base breakdown voltage	I <sub>C</sub> = -100 μA; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C		-50	-	-	V
V <sub>(BR)CEO</sub>	collector-emitter breakdown voltage	$I_C = -10 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-50	-	-	V
I <sub>CBO</sub>	collector-base cut-off current	V <sub>CB</sub> = -50 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	-100	nA
I <sub>CEO</sub>	collector-emitter cut-off current	V <sub>CE</sub> = -50 V; I <sub>B</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	-0.5	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = -5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	-0.65	mA
h <sub>FE</sub>	DC current gain	$V_{CE} = -5 \text{ V}; I_{C} = -50 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$		70	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C$ = -50 mA; $I_B$ = -2.5 mA; $T_{amb}$ = 25 °C		-	-	-100	mV
V <sub>I(off)</sub>	off-state input voltage	$V_{CE}$ = -5 V; $I_{C}$ = -100 $\mu$ A; $T_{amb}$ = 25 °C		-0.4	-0.65	-1	V
V <sub>I(on)</sub>	on-state input voltage	$V_{CE}$ = -0.3 V; $I_{C}$ = -20 mA; $T_{amb}$ = 25 °C		-0.5	-0.95	-1.4	V
R1	bias resistor 1 (input)		[1]	1.54	2.2	2.86	kΩ
R2/R1	bias resistor ratio		[1]	4.1	4.55	5	
C <sub>c</sub>	collector capacitance	$V_{CB}$ = -10 V; $I_E$ = 0 A; $i_e$ = 0 A; $f$ = 1 MHz; $T_{amb}$ = 25 °C		-	11	-	pF
f <sub>T</sub>	transition frequency	$V_{CE}$ = -5 V; $I_{C}$ = -50 mA; f = 100 MHz; $T_{amb}$ = 25 °C	[2]	-	140	-	MHz

- [1] See section "Test information" for resistor calculation and test conditions.
- [2] Characteristics of built-in transistor

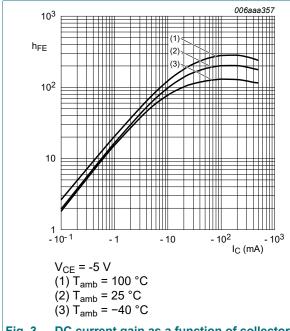


Fig. 3. DC current gain as a function of collector current; typical values

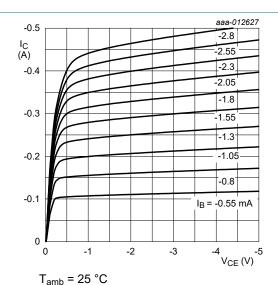
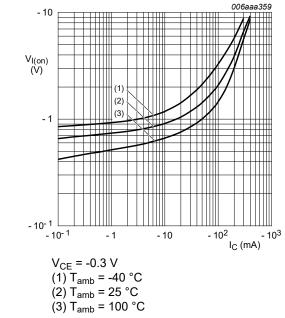
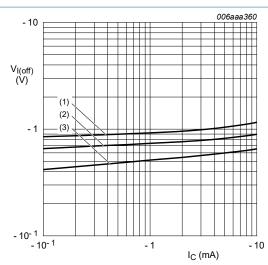


Fig. 4. Collector current as a function of collectoremitter voltage, typical values

### 50 V, 500 mA PNP/PNP Resistor-Equipped double Transistor (RET); R1 = 2.2 k $\Omega$ , R2 = 10 k $\Omega$

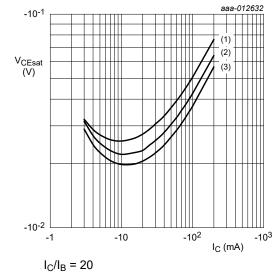






V<sub>CE</sub> = -5 V (1) T<sub>amb</sub> = -40 °C (2) T<sub>amb</sub> = 25 °C (3) T<sub>amb</sub> = 100 °C

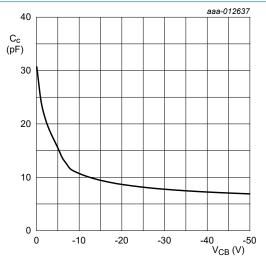
Off-state input voltage as a function of collector current; typical values



(1) T<sub>amb</sub> = 100 °C (2) T<sub>amb</sub> = 25 °C

(3)  $T_{amb} = -40 \, ^{\circ}C$ 

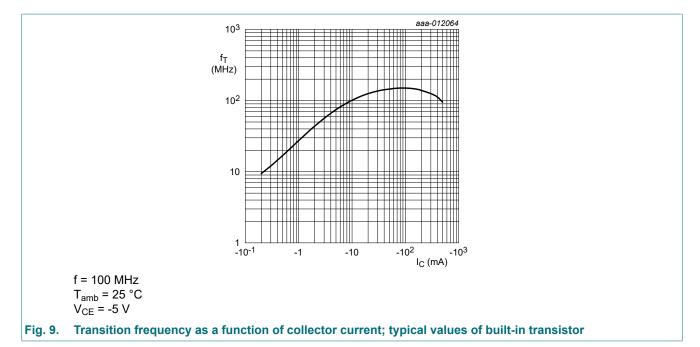
Fig. 7. Collector-emitter saturation voltage as a function of collector current; typical values



f = 1 MHz $T_{amb}$  = 25 °C

Fig. 8. Collector capacitance as a function of collectorbase voltage; typical values

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50 V, 500 mA PNP/PNP Resistor-Equipped double Transistor (RET); R1 = 2.2 k $\Omega$ , R2 = 10 k $\Omega$ 

## 11. Test information

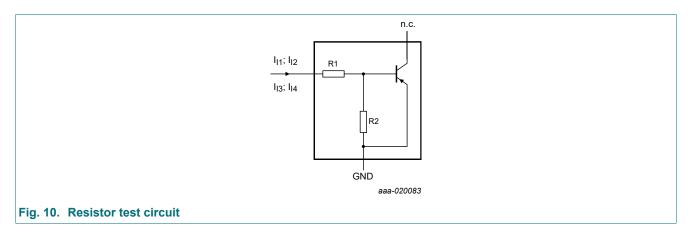
#### **Resistor calculation**

· Calculation of bias resistor 1 (R1)

$$RI = \frac{V(I12) - V(I11)}{I12 - I11}$$

· Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I14) - V(I13)}{R1 \cdot (I14 - I13)} - 1$$



#### **Resistor test conditions**

**Table 8. Resistor test conditions** 

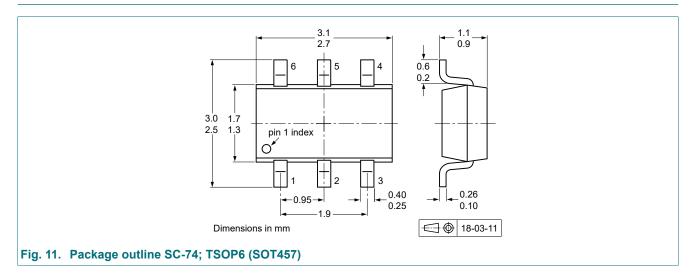
R1 (kΩ)	R2 (kΩ)	Test conditions	lest conditions				
		I <sub>I1</sub>	I <sub>12</sub>	I <sub>13</sub>	I <sub>14</sub>		
2.2	10	-0.7 mA	-0.8 mA	0.45 mA	0.55 mA		

## **Quality information**

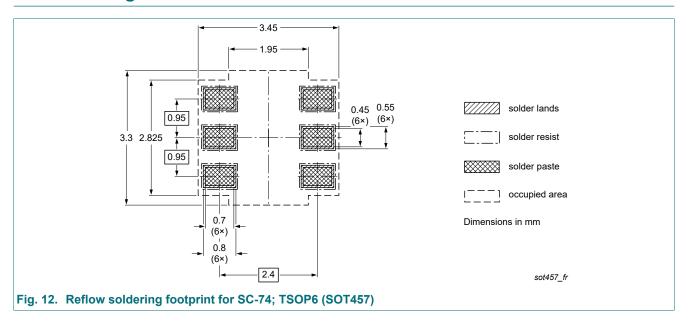
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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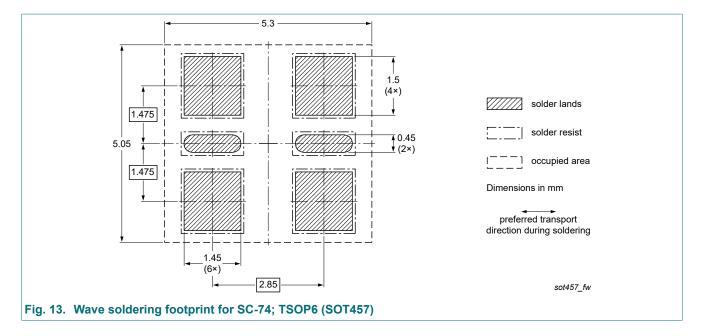
## 12. Package outline



## 13. Soldering



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## 14. Revision history

### Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PIMP32-Q v.1	20220216	Product data sheet	-	-

#### 50 V, 500 mA PNP/PNP Resistor-Equipped double Transistor (RET); R1 = 2.2 k $\Omega$ , R2 = 10 k $\Omega$

## 15. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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